# NSN 5961-01-123-2084

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.165 inches

# **Overall Diameter:**

0.225 inches

#### **End Application:**

4920-01-054-8588 e/i fscm 81755

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

#### Mounting Method:

Press fit and unthreaded hole

#### Features Provided:

# Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage/static/emitter open and 22.0 collector to emitter voltage/static/base open and 3.3 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

150.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

2.7 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

12436-6011088 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

1 flange and 2 uninsulated wire lead

Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

Fiig:

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